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Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

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Plastic Medium-Power Silicon NPN Transistors

This series of plastic, medium-power silicon NPN transistors are designed for use as audio amplifiers and drivers utilizing complementary or quasi complementary circuits.

Features

- High DC Current Gain
- BD 135, 137, 139 are complementary with BD 136, 138, 140
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant*

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage BD135G BD137G BD139G	V _{CEO}	45 60 80	Vdc
Collector-Base Voltage BD135G BD137G BD139G	V _{CBO}	45 60 100	Vdc
Emitter-Base Voltage	V _{EBO}	5.0	Vdc
Collector Current	Ι _C	1.5	Adc
Base Current	Ι _Β	0.5	Adc
Total Device Dissipation @ T _A = 25°C Derate above 25°C	P _D	1.25 10	Watts mW/°C
Total Device Dissipation @ T _C = 25°C Derate above 25°C	P _D	12.5 100	Watts mW/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

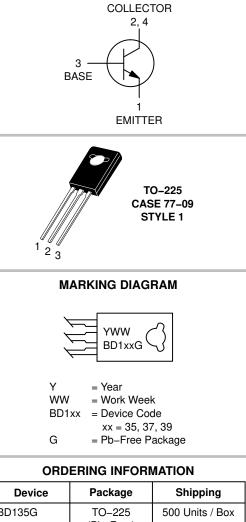
Characteristic	Symbol	Мах	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	10	°C/W
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	100	°C/W



ON Semiconductor®

http://onsemi.com

1.5 A POWER TRANSISTORS NPN SILICON 45, 60, 80 V, 12.5 W



BD135G	TO–225 (Pb–Free)	500 Units / Box
BD135TG	TO–225 (Pb–Free)	50 Units / Rail
BD137G	TO–225 (Pb–Free)	500 Units / Box
BD139G	TO–225 (Pb–Free)	500 Units / Box

*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

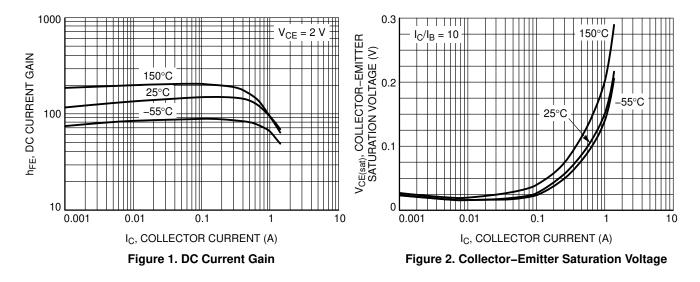
ELECTRICAL CHARACTERISTICS ($T_C = 25^{\circ}C$ unless otherwise noted)			
Characteristic	Symbol		

Characteristic	Symbol	Min	Max	Unlt
$\begin{array}{l} \mbox{Collector-Emitter Sustaining Voltage}^{*} \\ (I_{C} = 0.03 \mbox{ Adc}, I_{B} = 0) \\ \mbox{ BD135G} \\ \mbox{ BD137G} \\ \mbox{ BD139G} \end{array}$	BV _{CEO} *	45 60 80	- - -	Vdc
	I _{CBO}		0.1 10	μAdc
Emitter Cutoff Current ($V_{BE} = 5.0 \text{ Vdc}, I_C = 0$)	I _{EBO}	-	10	μAdc
$ \begin{array}{l} \text{DC Current Gain} \\ (I_C = 0.005 \text{ A}, \text{ V}_{CE} = 2 \text{ V}) \\ (I_C = 0.15 \text{ A}, \text{ V}_{CE} = 2 \text{ V}) \\ (I_C = 0.5 \text{ A} \text{ V}_{CE} = 2 \text{ V}) \end{array} $	h _{FE} *	25 40 25	250 -	-
Collector–Emitter Saturation Voltage* ($I_C = 0.5$ Adc, $I_B = 0.05$ Adc)	V _{CE(sat)} *	-	0.5	Vdc
Base-Emitter On Voltage* ($I_C = 0.5 \text{ Adc}, V_{CE} = 2.0 \text{ Vdc}$)	V _{BE(on)} *	-	1	Vdc

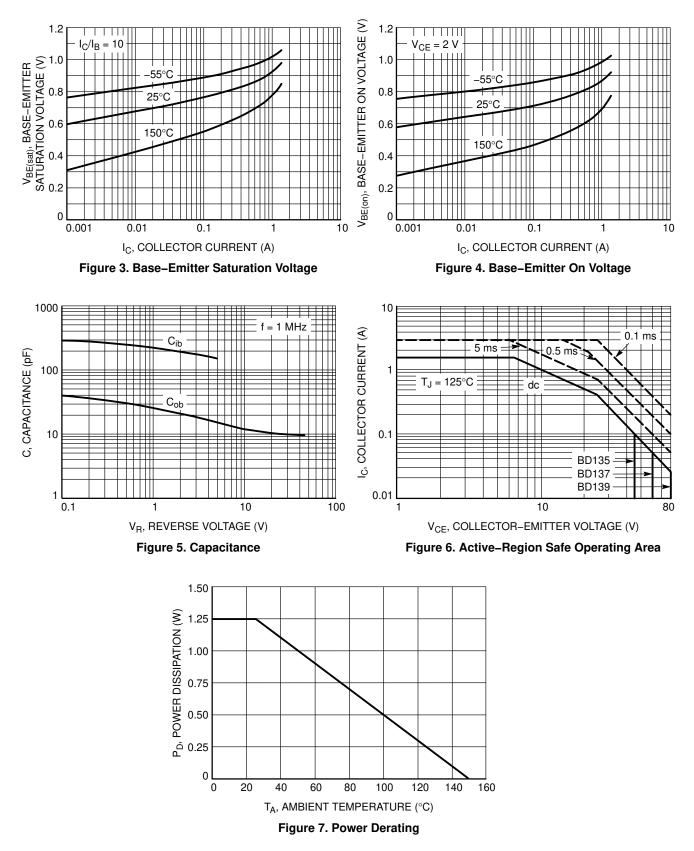
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

*Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2.0%.

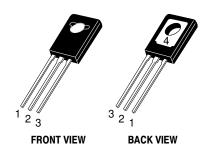
TYPICAL CHARACTERISTICS



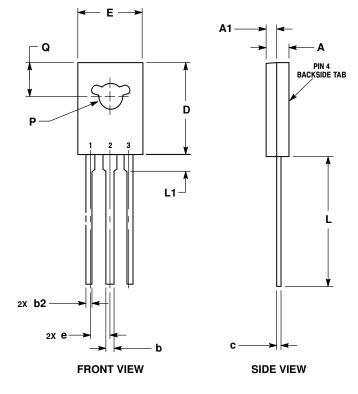
TYPICAL CHARACTERISTICS



PACKAGE DIMENSIONS



TO-225 CASE 77-09 ISSUE AC



NOTES: 1. DIMENSIONING AND TOLERANCING PER

 DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
CONTROLLING DIMENSION: MILLIMETERS.

CONTROLLING DIMENSION: MILLIMETERS.
NUMBER AND SHAPE OF LUGS OPTIONAL.

	MILLIMETERS		
DIM	MIN	MAX	
Α	2.40	3.00	
A1	1.00	1.50	
b	0.60	0.90	
b2	0.51	0.88	
C	0.39	0.63	
D	10.60	11.10	
Е	7.40	7.80	
е	2.04	2.54	
L	14.50	16.63	
L1	1.27	2.54	
Р	2.90	3.30	
Q	3.80	4.20	
STYLE 1: PIN 1. EMITTER			
2 4 COLLECTOR			

3. BASE

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